

MILITARY SPECIFICATION

SEMICONDUCTOR DEVICE, DIODE, SILICON, HIGH-CONDUCTANCE

TYPE JAN-1N3207

This amendment forms a part of Military Specification MIL-S-19500/230C, dated 12 February 1965, and is mandatory for use by all Departments and Agencies of the Department of Defense.

Page 1, paragraph 1.1: Delete and substitute:

"1.1 Scope. This specification covers the detail requirements for silicon, high-conductance, organic-polymer-encapsulated diodes, for use as thin-film or magnetic-core drivers."

Page 2, add the following paragraph:

"3.3.1 Encapsulating materials. Encapsulating materials for all devices shall only be organic polymers."

Custodians:

Army - EL  
Navy - EC  
Air Force - 11

Preparing activity:

Army - EL  
(Project 5961-0097)

Review activities:

Army - EL, MU, MI  
Navy - SH, EC  
Air Force - 11, 17, 85  
DSA - ES

User activities:

Army - EL, SM  
Navy - MC, CG, AS, OS  
Air Force - 19